# SCALE-UP: An implementation of Second-Principles DFT

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#### Louvain May 2019



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## Collaborators

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Funding



RyC programme

### What can we do with first-principles simulations?

Predict material properties using just fundamental constants

Little input from user necessary to obtain reliable information

 $\hat{H}\Psi = E\Psi$  or DFT



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Predictive
 Accurate energies
 Equilibrium geometries

 $\hat{H}\Psi = E\Psi$  or DFT



✓ Predictive
 ✓ Accurate energies
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 ~ Excited states
 ~ Temperature
 ~ Defects

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- Predictive
   Accurate energies
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- $\sim\,$  Excited states
- $\sim$  Temperature
- $\sim\,$  Defects
- ✗ Scaling (typically N<sup>3</sup>)

Wealth of information that could be difficult to obtain experimentally

Scale of interest  $\checkmark$  Nanoscale ( $\approx 10 - 100$ nm)  $\thickapprox$  DFT  $\approx 1$  nm



Nanowires



skyrmion in MnSi

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Thermoelectrics, polarons...





skyrmion in MnSi

Non-equilibrium states

- Resistivity
- Charge diffusion
- ✓ Reaction yield

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Thermoelectrics, polarons...

Disorder

- ✓ Domains
  - / Thermal

Defects (polarons, impurities...)





skyrmion in MnSi

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Ferroelectric domains in BiFeO3

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Thermoelectrics, polarons...

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skyrmion in MnSi

Nanowires Non-equilibrium states

- Resistivity
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Ferroelectric domains in BiFeO3

- Perturbations/disorder are key elements in experiments.
- Room temperature is fundamental for applications.

First principles simulations deal with all electrons in the system:



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Response to perturbations usually involves a few active electron/holes

First principles simulations deal with all electrons in the system:

Number of electrons grows fast Hamiltonian  $\sim N^2$  Diagonalization  $\sim N^3$ 



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Can we select the level of fidelity of our calculations? Can we make it efficient? Can we reliably parameterize it?

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Second-principles Density Functional Methods

### Basic concepts

We want to separate the active electrons that participate in physical properties from all others.

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The total density is separated in reference and deformation densities:

$$n(\vec{r}) = n_0(\vec{r}) + \delta n(\vec{r})$$

 $n_0$  = reference density  $\delta n$  = deformation density

### Approximating the DFT energy

Our starting point is the DFT energy

$$E_{\text{DFT}} = \sum_{j\vec{k}} o_{j\vec{k}} \left\langle \psi_{j\vec{k}} \right| \hat{t} + v_{\text{ext}} \left| \psi_{j\vec{k}} \right\rangle + \frac{1}{2} \iint \frac{n(\vec{r})n'(\vec{r}')}{|\vec{r} - \vec{r}'|} d^3r d^3r' + E_{\text{xc}}[n] + E_{\text{nn}}$$

We want to write the energy in terms of the reference and deformation densities.

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The only difficulty is the exchange-correlation energy that we expand in terms of  $\delta n$  (see e. g. M. Elstner et al., *Phys. Rev. B*, 58, 7260 (1998)):

$$E_{\rm xc}[n] = E_{\rm xc}[n_0] + \int \left. \frac{\delta E_{\rm xc}}{\delta n(\vec{r})} \right|_{n_0} \delta n(\vec{r}) d^3 r + \frac{1}{2} \iint \left. \frac{\delta^2 E_{\rm xc}}{\delta n(\vec{r}) \delta n(\vec{r}')} \right|_{n_0} \delta n(\vec{r}) \delta n(\vec{r}') d^3 r d^3 r' + \cdots$$

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As in usual TB-DFT approximations, we cut at second-order

$$E_{\rm DFT} \approx E = E^{(0)} + E^{(1)} + E^{(2)}$$

However, we group the terms in a different way to TB-DFT.



Material simulations allow for various approaches

First principles methods are atomistic with flexible detailed bonding FP or TB-DFT



Based on atoms



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 $\mathsf{Atoms} \Longrightarrow \mathsf{FP} \Longrightarrow \mathsf{Materials}$ 



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Based on atoms



💕 = 💸

Based on materials



 $\begin{array}{l} \mathsf{Atoms} \Longrightarrow \mathsf{FP} \Longrightarrow \mathsf{Materials} \Longrightarrow \mathsf{SP} \Longrightarrow \mathsf{Large-scale} \\ \mathsf{Accurate\ properties\ do\ not\ require\ bond-breaking!} \end{array}$ 



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Precise, small, material-adapted basis  $\rightarrow$  Wannier-like functions I. Souza et al., *Phys. Rev. B*, 65, 035109 (2001)

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## Energy terms: $E = E^{(0)} + E^{(1)} + E^{(2)}$ Reference

This term is the full DFT energy for the reference state:

$$E^{(0)} = \sum_{j\vec{k}} o^{0}_{j\vec{k}} \left\langle \psi^{0}_{j\vec{k}} \right| \hat{t} + v_{\text{ext}} \left| \psi^{0}_{j\vec{k}} \right\rangle + \frac{1}{2} \iint \frac{n_{0}(\vec{r})n'_{0}(\vec{r}')}{|\vec{r} - \vec{r}'|} d^{3}r d^{3}r' + E_{\text{xc}}[n_{0}] + E_{nn}$$

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No approximations

At difference with usual TB-DFT this term is very large and contains most of the total energy. It can be made really accurate.



The reference state is defined for all geometries

 $E_0(\eta, \{\vec{u}\})$  is the energy surface for the reference state

It can be represented by a high-quality model potential. J. Wojdeł et al., *JPCM*, 25, 305401 (2013)

## This lattice Hamiltonian is implemented in Multibinit!

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# Energy terms: $E = E^{(0)} + E^{(1)} + E^{(2)}$ One electron

Full DFT energy for n<sub>0</sub>

#### Reference

► Force field

#### Multibinit

 $E^{(1)}$  contains differences in one-electron energies

 $E^{(1)} = \sum_{j\vec{k}} \left[ o_{j\vec{k}} \left\langle \psi_{j\vec{k}} \right| \hat{h}_0 \left| \psi_{j\vec{k}} \right\rangle - o_{j\vec{k}}^0 \left\langle \psi_{j\vec{k}}^0 \right| \hat{h}_0 \left| \psi_{j\vec{k}}^0 \right\rangle \right]$ 





where  $\hat{h}_0$  is the Kohn-Sham Hamiltonian for the reference density:

$$\hat{h}_0 = \hat{t} + v_{\text{ext}} + v_{\text{H}}(n_0) + v_{\text{xc}}[n_0]$$

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$$= \sum_{ab} D_{ab} \gamma_{ab} \quad (\text{Wannier basis, } \chi_a)$$
$$\delta n(\vec{r}) = \sum_{ab} D_{ab} \chi_a^*(\vec{r}) \chi_b(\vec{r})$$





 $\gamma_{\textit{ab}}$  takes the role of the hopping constant in TB schemes.

$$\gamma_{ab} = \int d^3 r \chi^*_a(\vec{r}) \hat{h}_0 \chi_b(\vec{r})$$

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Only depends on difference density!

# Energy terms: $E = E^{(0)} + E^{(1)} + E^{(2)}$ Two electron

Full DFT energy for n<sub>0</sub> F<sup>(0)</sup> Reference Force field Multibinit E<sup>(1)</sup> Depends only on difference density **One-electron** Tight-binding like  $E^{(2)}$  are interactions between 2 electrons ( $E^{(3)}$  3-electron, etc.):  $E^{(2)} = \frac{1}{2} \int d^3r \int d^3r' g(\vec{r}, \vec{r}', s, s') \delta n(\vec{r}, s) \delta n(\vec{r}', s')$ 

where g is a screened electron-electron interaction operator.

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# Energy terms: $E = E^{(0)} + E^{(1)} + E^{(2)}$ Calculation

Reference	► Full DFT energy for n <sub>0</sub>	F <sup>(0)</sup>
Reference	<ul><li>Force field</li><li>Multibinit</li></ul>	
One-electron	<ul><li>Depends only on difference density</li><li>Tight-binding like</li></ul>	E <sup>(1)</sup>
Two-electron	<ul><li>Depends only on difference density</li><li>Screened mean-field interactions</li></ul>	E <sup>(2)</sup>
<ul> <li>Accurate</li> </ul>		
<ul> <li>Fast</li> </ul>		
Valid for al	I kind of systems (magnetic, metallic,)	

### Electrostatics/Electron-lattice interactions

All interactions occur between localized objects:



At long-range (far-field regime) shape of source density is unimportant Multipolar expansion  $\gamma$  and U contain electrostatic (long-range) contributions Hartree/electron-nucleus

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Local dipoles:

- Atomic displacement  $\rightarrow Z^*$
- Hybridizations  $\rightarrow \langle \chi_{a} | \vec{r} | \chi_{b} \rangle$

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Potential approximated by field of point charges and dipoles localized at the reference geometry

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Model parameters  $\longrightarrow$  long and short range contributions.

#### Geometry dependence - Forces

Geometry is involved by expanding  $\gamma$  on the atomic positions:



$$\gamma_{\boldsymbol{ab}}^{\mathrm{sr}} = \gamma_{\boldsymbol{ab}}^{0} + \sum_{\boldsymbol{\lambda}\boldsymbol{\upsilon}} \left[ \vec{f}_{\boldsymbol{ab},\boldsymbol{\lambda}\boldsymbol{\upsilon}} \cdot \delta \vec{r}_{\boldsymbol{\lambda}\boldsymbol{\upsilon}} + \delta \vec{r}_{\boldsymbol{\lambda}\boldsymbol{\upsilon}} \cdot \overset{\leftrightarrow}{g}_{\boldsymbol{ab},\boldsymbol{\lambda}\boldsymbol{\upsilon}} \cdot \delta \vec{r}_{\boldsymbol{\lambda}\boldsymbol{\upsilon}} + \dots \right]$$

U,I should also depend on  $\delta \vec{r} \rightarrow$  neglected

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U,I should also depend on  $\delta \vec{r} \rightarrow$  neglected The forces are then obtained:

$$\vec{F}_{\lambda} = -\vec{\nabla}_{\lambda}E = -\vec{\nabla}_{\lambda}E^{(0)} - \sum_{ab} D_{ab}\vec{\nabla}_{\lambda}\gamma_{ab}.$$

#### Electronic contribution corrects the force field

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#### NiO - Insulator with highly correlated electrons:







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Magnetic Troperties				
Method	J <sub>1</sub> (meV)	J <sub>2</sub> (meV)		
neutron	1.4	-19.0		
LDA+U	2.6	-17.5		
SP-Ni(3d) + O(2p)	3.3	-17.6		

Magnatia Dranautian

Electronic/magnetic properties predicted at DFT level 2000 atoms single point 1 hour in 1 Desktop cpu (full diag)



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#### 2DEG at $SrTiO_3/LaAIO_3$ Interface



 $\mathsf{FP} \to \mathsf{M}$ . Stengel, *PRL*, 106, 136803 (2011)

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## Ferroelectric bubbles

SP can simulate ferroelectric bubble skyrmions in PbTiO<sub>3</sub>/SrTiO<sub>3</sub>





 $\blacktriangleright$   $\sim$  40000 atoms



- Tangential polarization to bubble Makes bubbles chiral Explains XCD signal
- ► Bubble shows non-trivial topology Planes → same topological charge
- S. Das et al., Nature, 568, 368 (2019)

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## The implementation of SP-DFT: $\operatorname{SCALE-UP}$



P. Garcia-Fernandez, J. Wojdeł, J. Iñiguez and J. Junquera Phys. Rev. B, **93**, 195137 (2016)

- Fully integrated electron+lattice models
- Single-points, Dynamics (isokinetic, Langevin), Montecarlo
- SCF with convergence acelerators
- ▶ TDDFT: Real-time density propagation,  $\vec{E}(t)$  fields

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- ► SCALE-UP python module: Running and analysis
- ► Model building suite: MODELMAKER

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- ► Future: Spin-orbit, defects (surfaces, interfaces, impurities...)
- ► Future: Pure density-matrix implementation

### The connection between SCALE-UP and MULTIBINIT

 $\ensuremath{\underline{\operatorname{SCALE-UP}}}$  can be run as a library by other codes



► It can provide  $E^{(0)}$ ,  $E^{(1)}+E^{(2)}$  or  $E^{(0)}+E^{(1)}+E^{(2)}$ 

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Distribution SCALE-UP  $\longrightarrow$  Attendance to workshop Rationale: Forming community, second-principles are not blackbox

Second Principles depend on First Principles to create models



**FP-SP** Interface

Very delicate process, we need:

- Accuracy: SP model needs to reproduce FP
- Lightweight: SP model needs to be efficient

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  - 2 Few and clean input parameters
  - **3** Systematically improvable models
  - Produces hopping, electron-lattice, electron-electron-parameters

#### Currently we have a $\operatorname{SCALE-UP}$ - $\operatorname{SIESTA}$ - $\operatorname{WANNIER90}$ Interface

## Modelmaker

The first step to create a model is to create a FP training set



Model Hamiltonian  $\longrightarrow$  capture FP physics

- Bands: Wannier Hamiltonian
- Electron-lattice terms: Change geometry on a supercell
- Electron-electron terms: Controlled perturbation of electrons

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The SIESTA-WANNIER90 interface...

Javier Junquera



## Modelmaker

Next we need to determine the terms that form the model



- The input is just 4 distances that determine the range of hopping, position, electron-lattice and electron-electron matrix elements.
- ► The code then filters the created terms using symmetry
- Finally, modelmaker calls SCALE-UP to determine the long-range corrections

## Modelmaker



- The code determines iteratively "best n-terms" models
- It provides with tools to check accuracy of the model and systematic error detection
- The user decides if model is good enough and how to improve

## Summary

- Second-Principles DFT bridges the gap between first-principles and model Hamiltonians
- The goal is getting closer to "Computational experiments"
   P. Garcia-Fernandez et al., PRB, 93, 195137 (2016)
  - J. Wojdeł et al., JPCM, 25, 305401 (2013)



- Current applications show the accuracy and versatility of method
   S. Das et al., *Nature*, 568, 368 (2019)
- Their use requires still a lot of user input Strong interactions with FP codes

## Thank you for your attention!